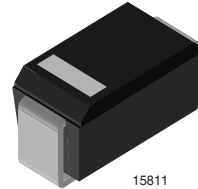


## Super Fast Avalanche SMD Rectifier

### Features

- Glass passivated junction
- Low reverse current
- Soft recovery characteristics
- Fast reverse recovery time
- Good switching characteristics
- Wave and reflow solderable



### Applications

Surface mounting

Fast rectifier

Freewheeling diodes in SMPS and converters

Snubber diodes

### Parts Table

Part	Type differentiation	Package
BYG20D	$V_R = 200 \text{ V @ } I_{FAV} = 1.5 \text{ A}$	DO-214AC
BYG20G	$V_R = 400 \text{ V @ } I_{FAV} = 1.5 \text{ A}$	DO-214AC
BYG20J	$V_R = 600 \text{ V @ } I_{FAV} = 1.5 \text{ A}$	DO-214AC

### Absolute Maximum Ratings

$T_{amb} = 25 \text{ }^\circ\text{C}$ , unless otherwise specified

Parameter	Test condition	Part	Symbol	Value	Unit
Reverse voltage = Repetitive peak reverse voltage		BYG20D	$V_R = V_{RRM}$	200	V
		BYG20G	$V_R = V_{RRM}$	400	V
		BYG20J	$V_R = V_{RRM}$	600	V
Peak forward surge current	$t_p = 10 \text{ ms}$ , half sinewave		$I_{FSM}$	30	A
Average forward current			$I_{FAV}$	1.5	A
Junction and storage temperature range			$T_J = T_{stg}$	- 55 to + 150	$^\circ\text{C}$
Pulse energy in avalanche mode, non repetitive (inductive load switch off)	$I_{(BR)R} = 1 \text{ A}$ , $T_J = 25 \text{ }^\circ\text{C}$		$E_R$	20	mJ

### Maximum Thermal Resistance

$T_{amb} = 25\text{ }^{\circ}\text{C}$ , unless otherwise specified

Parameter	Test condition	Part	Symbol	Value	Unit
Junction lead	$T_L = \text{const.}$ - -		$R_{thJL}$	25	K/W
Junction ambient	mounted on epoxy-glass hard tissue		$R_{thJA}$	150	K/W
	mounted on epoxy-glass hard tissue, 50 mm <sup>2</sup> 35 $\mu\text{m}$ Cu		$R_{thJA}$	125	K/W
	mounted on Al-oxid-ceramic (Al <sub>2</sub> O <sub>3</sub> ), 50 mm <sup>2</sup> 35 $\mu\text{m}$ Cu		$R_{thJA}$	100	K/W

### Electrical Characteristics

$T_{amb} = 25\text{ }^{\circ}\text{C}$ , unless otherwise specified

Parameter	Test condition	Part	Symbol	Min	Typ.	Max	Unit
Forward voltage	$I_F = 1\text{ A}$		$V_F$			1.3	V
	$I_F = 1.5\text{ A}$		$V_F$			1.4	V
Reverse current	$V_R = V_{RRM}$		$I_R$			1	$\mu\text{A}$
	$V_R = V_{RRM}, T_j = 100\text{ }^{\circ}\text{C}$		$I_R$			10	$\mu\text{A}$
Reverse recovery time	$I_F = 0.5\text{ A}, I_R = 1\text{ A}, i_R = 0.25\text{ A}$		$t_{rr}$			75	ns

### Typical Characteristics ( $T_{amb} = 25\text{ }^{\circ}\text{C}$ unless otherwise specified)

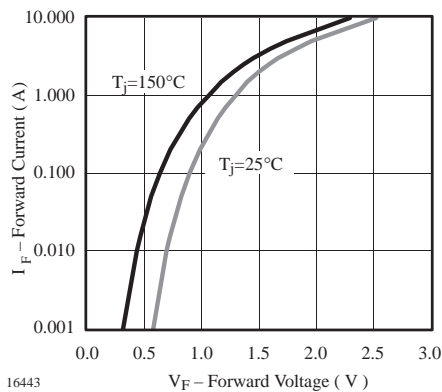


Figure 1. Forward Current vs. Forward Voltage

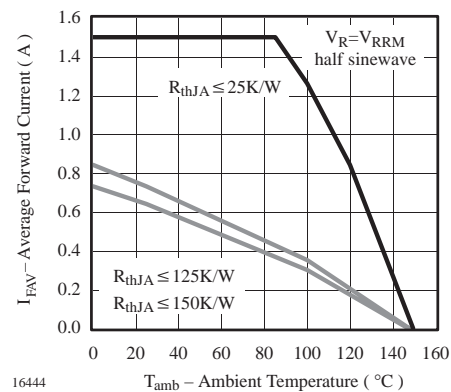


Figure 2. Max. Average Forward Current vs. Ambient Temperature

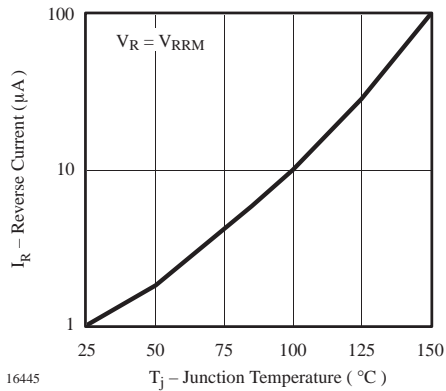


Figure 3. Reverse Current vs. Junction Temperature

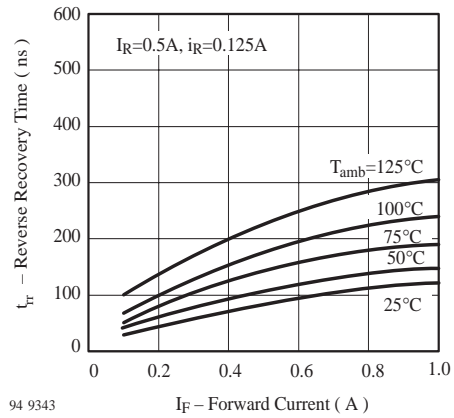


Figure 6. Max. Reverse Recovery Time vs. Forward Current

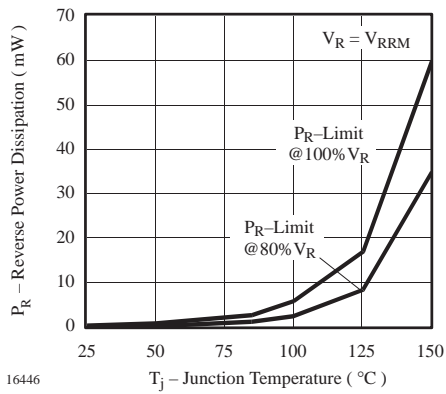


Figure 4. Max. Reverse Power Dissipation vs. Junction Temperature

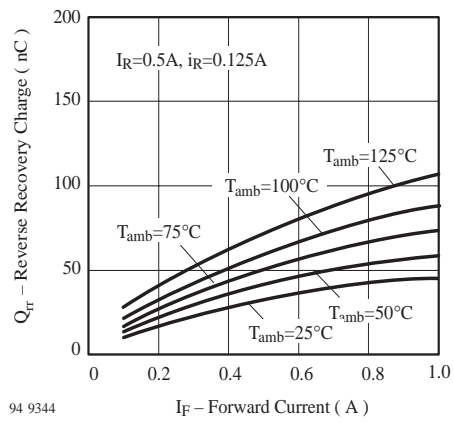


Figure 7. Max. Reverse Recovery Charge vs. Forward Current

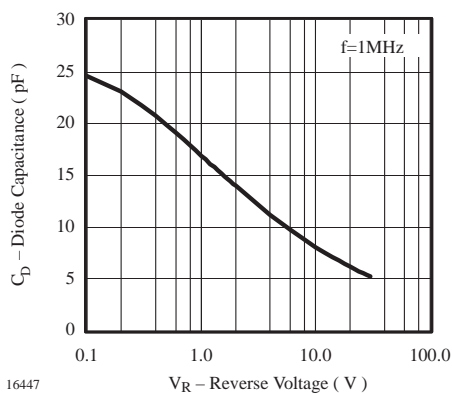


Figure 5. Diode Capacitance vs. Reverse Voltage

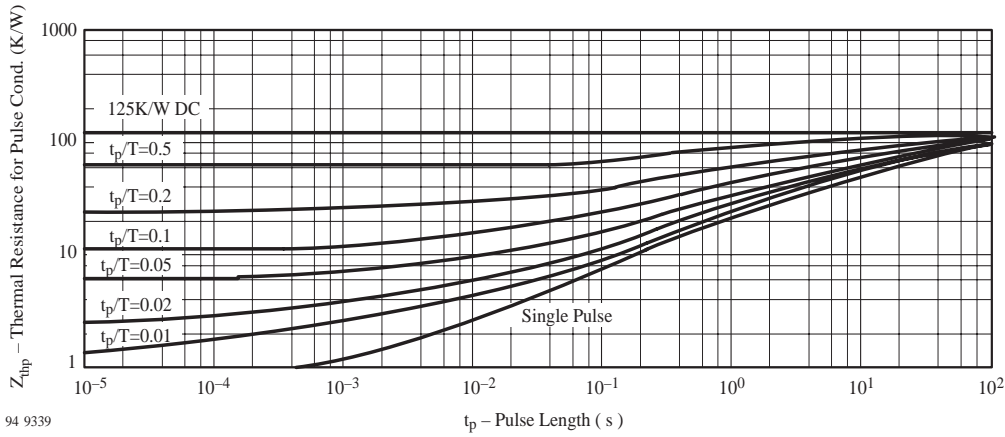
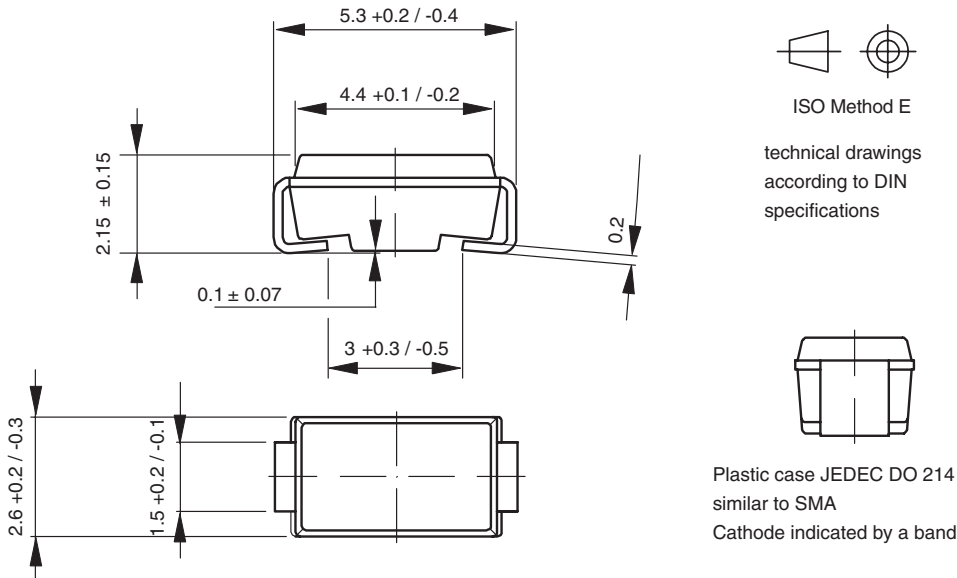


Figure 8. Thermal Response

## Package Dimensions in mm



14275-1